



SP4T High Isolation PIN Diode Switch DC to 20 GHz, 38 dB, 24 dBm, 3.8 dB Loss and SMA

The FMSW5006 is a Single Pole Four Throw (SP4T) Absorptive Switch that covers a wide frequency band from DC to 20 GHz. purpose design utilizes GaAs MESFET MMIC technology that has extremely fast switching speed levels of 17 nsec. Additional typical performance includes 42 dB Isolation up to 12 GHz, and 2.7 dB Insertion Loss at 6 GHz.

The design also incorporates CMOS driver circuitry that allows a single +5V biased voltage at very low DC current levels. The drop-in package is hermetically sealed with field replaceable SMA connectors. Operating temperature range is -55°C to +85°C. And for added confidence, this rugged package assembly is designed to meet MIL-STD-883 test conditions for Hermeticity and Temperature Cycle.

This High Isolation PIN Diode Switch is part of Fairview Microwave's expanding line of PIN Diode Switch offerings. These parts offer high isolation performance in a very wide Frequency Range coverage and outstanding electrical performance in the band.

Electrical Specifications

Description	Min	Тур	Max	Units
Frequency Range	DC		20	GHz
Insertion Loss		3.8		dB
Isolation		38		dB
Control Input		TTL		
Power Handling		+24		dBm

Performance by Frequency

Descr	iption	Frequency	Min.	Тур.	• Magar • Mager Op Units
		DC - 6 Ghz		-2.7	Space Systems Test Instrumen
Insertion Loss		DC - 12 Ghz		-2.8	Telecom Infrast
		DC - 20 Ghz		-3.8	• Base station In
		DC - 6 Ghz	44	48	
Isolation		DC - 12 Ghz	36	42	dB
		DC - 20 Ghz	35	38	
Return Loss	"On State"	DC - 12 Ghz DC - 20 Ghz		12 10	dB
Return Loss RF1, RF2	"Off State"	DC - 12 Ghz DC - 20 Ghz		15 10	dB
Input Power for 1 dB Compre	ssion	0.5 - 20 Ghz	+20.5	+24	dBm
Input Third Order Intercept (Two-Tone Input Power = +7	dBm Each Tone)	0.5 - 20 Ghz	+36.5	+40	dBm
Switching Characteristics tRISE, tFALL (10/90% RF) tON, tOFF (50% CTL to 10/90	0% RF)	DC - 20 Ghz		17 130	ns Fairview Microwaye



Features:

- SP4T Absorptive Switch Design
- GaAs MESFET MMIC Technology
- Ultra Fast Switching Speed 17 nsec typical
- High Isolation 42 dB typical up to 12 GHz
- Low Insertion Loss 2.7 dB typical at 6 GHz
- CMOS Driver Circuit
- Hermetically Sealed Module
- Field Replaceable **SMA Connectors**
- -55°C to +85°C Operating Temperature
- · Designed to meet MIL-STD-883 Conditions

Applications:

- · Electronic Warfare
- Electronic Countermeasures
- Microwave Radio
- VSAT
- Dodor
- ntation
- tructure
- nfrastructure

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Absolute Maximum Rating

RF Input Power		+24 dBm
	Supply Voltage (Vdc)	+7V
	Control Voltage Range (Vctl)	-0.5V to Vdc +1V
	Storage Temperature	-65 to +150 °C
	Operating Temperature	-55 to +85 °C

Control Voltages

State	Bias Condition	
High	+3.0 to Vdc @ 1 mA Typ.	
Low	0 to +1.5V @ 20 μA Typ.	

Bias Voltage & Current

Vdc Range = +5 Vdc ± 10%		
Vdc (V)	ldc (Typ.) (mA)	
+5.0	1.4	

(Bias current increases with switching rate to 15 - 20 mA.)

Truth Table

Control Input	Signal P	ath State		
VCTL1	VCTL2	RFC to:		
LOW	LOW	RF1		
LOW	HIGH	RF2		
HIGH	LOW	RF3		
HIGH	HIGH	RF4		

Mechanical Specifications

Size

Length 1.68 in [42.67 mm] Width/Dia. 1.6 in [40.64 mm] Height 0.325 in [8.26 mm]

Environmental Specifications By Design

Temperature

Operating Range -55 to +85 deg C Storage Range -65 to +150 deg C

Temperature Cycling

MIL-STD-883, Method 101C, Cond B

Hermetic Seal Gross Leak MIL-STD-883 Method 1014C1/Fine Leak MIL-STD-883, Method

1014A2, 5 x 10-8 atm cc

ESD Sensitivity ESD Sensitive Material, Transport material in Approved ESD bags. Handle only in

ESD Workstation.



Compliance Certifications (see product page for current document)

Plotted and Other Data

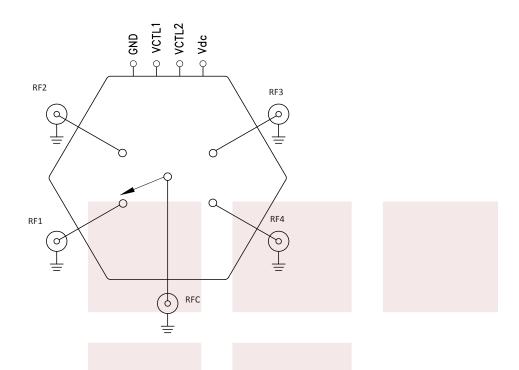
Notes:

Values at +25 °C, sea level

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Pin Descriptions

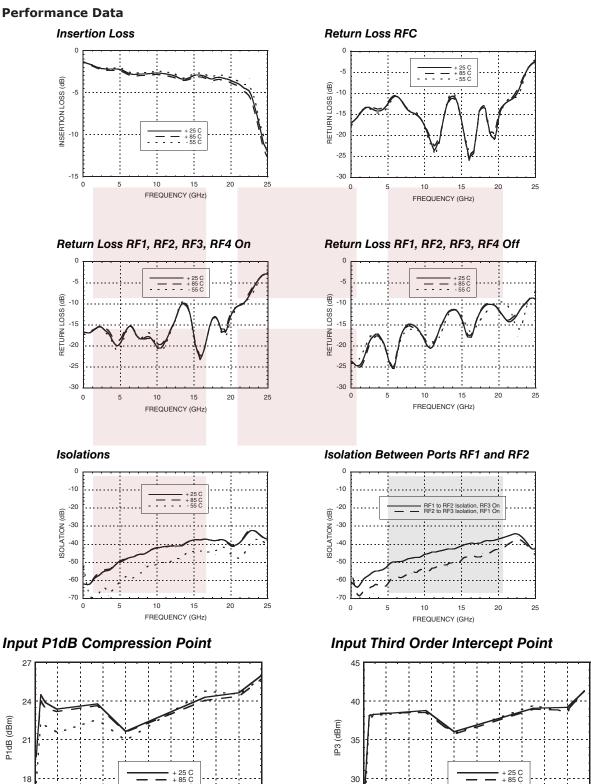
Pin Number	Function	Description	Interface Schematic
1	GND	Power supply ground.	⊖ GND =
			(Internal Driver)
2, 3	Vctl1, 2	CMOS interface, control voltages per table. Requires active pull up to +5V (V _{dc}).	Vctl1,20 4700 2ener 4700 -5V (Internal)
4	Vdc	Supply voltage	
5 - 9	RFC, RF1, RF2, RF3, RF4	RF connector, SMA female, field replaceable. These pins are DC coupled and matched to 50 Ohms. DC blocking capacitors are required if external RF line potential is not equal to 0V.	RFC PF1-RF4





Typical Performance Data

P1dB (dBm)



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FREQUENCY (GHz)

 FREQUENCY (GHz)





SP4T High Isolation PIN Diode Switch DC to 20 GHz, 38 dB, 24 dBm, 3.8 dB Loss and SMA from Fairview Microwave is instock and available to ship same-day. All of our RF/microwave products are available off-the-shelf from our ISO 9001:2008 certified facilities in Allen, Texas. Fairview Microwave is RF on-demand.

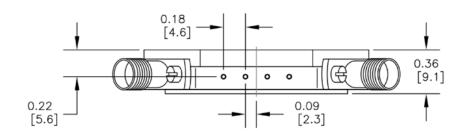
For additional information on this product, please click the following link: SP4T High Isolation PIN Diode Switch DC to 20 GHz, 38 dB, 24 dBm, 3.8 dB Loss and SMA FMSW5006

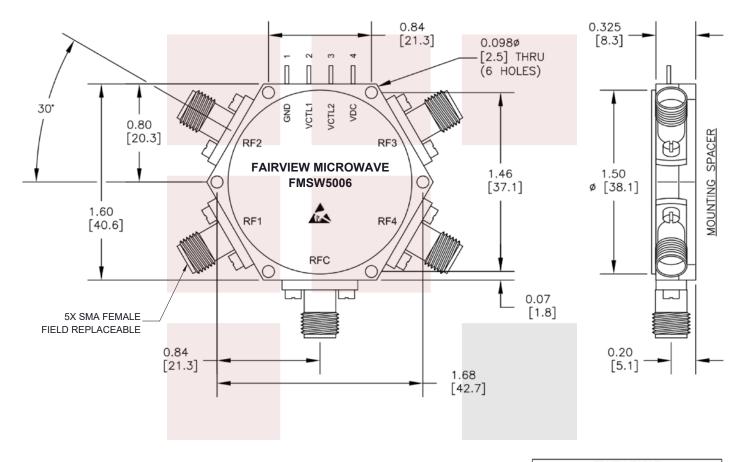
URL: https://www.fairviewmicrowave.com/high-isolation-pin-diode-switch-20-ghz-38db-3.8db-fmsw5006-p.aspx











STANDARD TOLERANCES

.X ±0.2 .XX ±0.01 .XXX ±0.005

*STANDARD TOLERANCES APPLY ONLY TO DIMENSIONS IN INCHES

TRUTH TABLE					
CONTROL INPUT SIGNAL PATH STATE					
VCTL1	VCTL2	RFC to:			
LOW	LOW	RF1			
LOW	HIGH	RF2			
HIGH	LOW	RF3			
HIGH	HIGH	RF4			

Fairview Microwave	NOTES: 1. UNLESS OTHERWISE SPECIFIED ALL DIMENSIONS ARE NOMINAL. 2. ALL SPECIFICATIONS ARE SUBJECT TO CHANGE WITHOUT NOTICE AT ANY TIME. 3. DIMENSIONS ARE IN INCHES [mm].					
SP4T High Isolation PIN Diode Switch DC to 20 GHz,	DWG NO FMSW5006			CAGE CODE 3FKR5		
38 dB, 24 dBm, 3.8 dB Loss and SMA	CAD FILE 05/21/18	SHEET 1 OF 1	SCAL	E N/A	SIZE A	7361